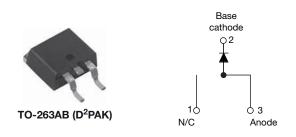
VS-20TQ035SPbF, VS-20TQ040SPbF, VS-20TQ045SPbF

Vishay Semiconductors

High Performance Schottky Rectifier, 20 A



www.vishay.com

SHA

PRODUCT SUMMARY	
Package	TO-263AB (D ² PAK)
I _{F(AV)}	20 A
V _R	35 V, 40 V, 45 V
V _F at I _F	0.51 V
I _{RM}	105 mA at 125 °C
T _J max.	150 °C
Diode variation	Single die
E _{AS}	27 mJ

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance



HALOGEN

FREE

- Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	20	A		
V _{RRM}	Range	35 to 45	V		
I _{FSM}	t _p = 5 μs sine	1800	A		
V _F	20 A _{pk} , T _J = 125 °C	0.51	V		
TJ	Range	-55 to +150	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-20TQ035SPbF	VS-20TQ040SPbF	VS-20TQ045SPbF	UNITS
Maximum DC reverse voltage V _R 35 40 45		45	V		
Maximum working peak reverse voltage	V _{RWM}		40	40	v

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS	
Maximum average forward current, see fig. 5	I _{F(AV)}	50 % duty cycle at T_{C} = 116 °C	C, rectangular waveform	20		
Maximum peak one cycle non-repetitive		5 µs sine or 3 µs rect. pulse	Following any rated load	1800	Α	
surge current, see fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	condition and with rated V _{RRM} applied	400		
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 4 \text{ A}, L = 3.40 \text{ cm}$	mH	27	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T_J maxim		4	А	

Revision: 08-Dec-14 1 Document Number: 94168 For technical questions within your region: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



www.vishay.com

Vishay Semiconductors

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST COND	DITIONS	VALUES	UNITS
		20 A	T.I = 25 °C	0.57	
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	40 A	$1_{\rm J} = 25$ C	0.73	V
	VFM ()	20 A	T 105 %C	0.51	
		40 A	T _J = 125 °C	0.67	
Maximum reverse leakage current	I _{BM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated $V_{\rm B}$	2.7	mA
See fig. 2	'RM \''	T _J = 125 °C	VR - naleu VR	105	IIIA
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal range	100 kHz to 1 MHz), 25 °C	1400	pF
Typical series inductance	L _S	Measured lead to lead 5 mm	from package body	8.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

/ISHAY

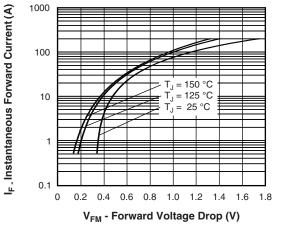
 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range)	T _J , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation See fig. 4	1.50	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	0/10
Approximate weight				2	g
Approximate weight				0.07	oz.
Mounting torque	minimum			6 (5)	kgf ⋅ cm
Mounting torque	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-263AB (D ² PAK)	20TQ	045S

VS-20TQ035SPbF, VS-20TQ040SPbF, VS-20TQ045SPbF

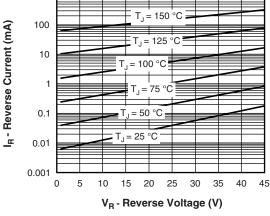
1000

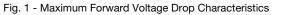
Vishay Semiconductors

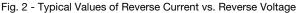


www.vishay.com

ISHAY







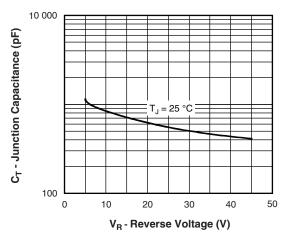


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

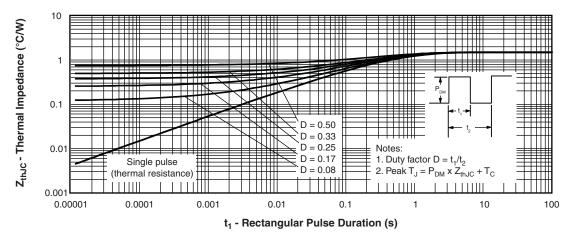


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

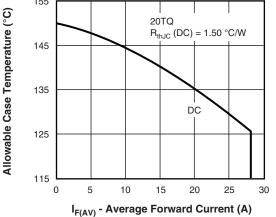
 Revision: 08-Dec-14
 3
 Document Number: 94168

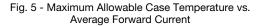
 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

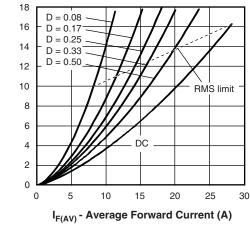
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



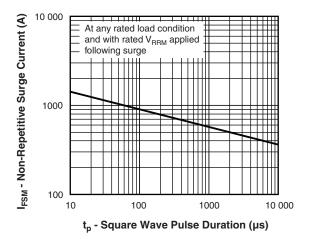
Average Power Loss (W)













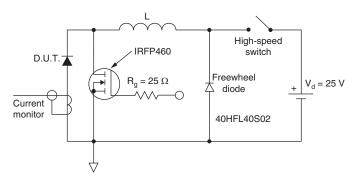


Fig. 8 - Unclamped Inductive Test Circuit

VS-20TQ035SPbF, VS-20TQ040SPbF, VS-20TQ045SPbF



www.vishay.com

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code	VS-	20	т	Q	045	S	TRL	PbF
		2	3	4	5	6	7	8
	1 - 2 - 3 - 4 - 5 - 6 -	Cur Pac Sch	nay Serr rent ratii kage: T iottky "Q tage rati D ² PAK	ng (20 A = TO-22 " series	.) 20	035 = 3 040 = 4 045 = 4	10 V	
	7 -	• TI • TI	one = tu RL = tap RR = tap ⁻ = lead	be and re	eel (left eel (righ		,	

ORDERING INFORMAT	I ON (Example)		
PREFERRED P/N	QUANTITY PER REEL	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-20TQ035SPBF	50	1000	Antistatic plastic tubes
VS-20TQ035STRRPBF	800	800	13" diameter plastic tape and reel
VS-20TQ035STRLPBF	800	800	13" diameter plastic tape and reel
VS-20TQ035-1PBF	50	1000	Antistatic plastic tubes
VS-20TQ040SPBF	50	1000	Antistatic plastic tubes
VS-20TQ040STRRPBF	800	800	13" diameter plastic tape and reel
VS-20TQ040STRLPBF	800	800	13" diameter plastic tape and reel
VS-20TQ040-1PBF	50	1000	Antistatic plastic tubes
VS-20TQ045SPBF	50	1000	Antistatic plastic tubes
VS-20TQ045STRRPBF	800	800	13" diameter plastic tape and reel
VS-20TQ045STRLPBF	800	800	13" diameter plastic tape and reel
VS-20TQ045-1PBF	50	1000	Antistatic plastic tubes

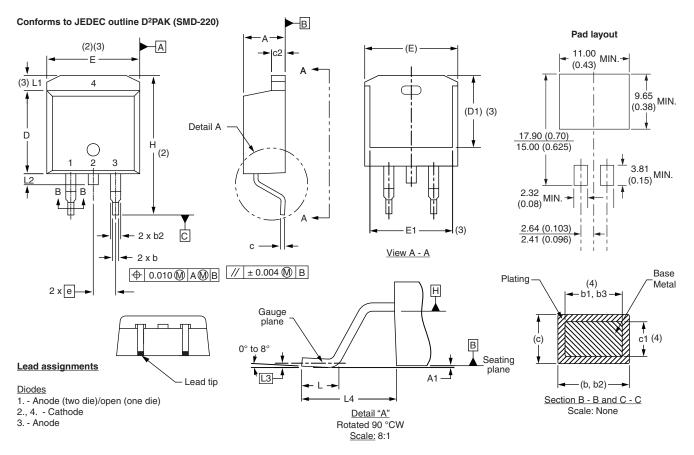
LINKS TO RELATED DOCUMENTS				
Dimensions	TO-263AB (D ² PAK)	www.vishay.com/doc?95046		
Dimensions	TO-262AA	www.vishay.com/doc?95014		
Part marking information		www.vishay.com/doc?95008		
Packaging information		www.vishay.com/doc?95032		

 Revision: 08-Dec-14
 5
 Document Number: 94168

 For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com
 THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000

Vishay Semiconductors

D²PAK, TO-262



DIMENSIONS - D²PAK in millimeters and inches

SHA

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
с	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54	BSC	0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25	BSC	0.010	BSC	
L4	4.78	5.28	0.188	0.208	

INCHES

MILLIMETERS

⁽⁷⁾ Outline conforms to JEDEC outline TO-263AB

Notes

 $^{(1)}\,$ Dimensioning and tolerancing per ASME Y14.5 M-1994 $\,$

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- ⁽⁴⁾ Dimension b1 and c1 apply to base metal only
- ⁽⁵⁾ Datum A and B to be determined at datum plane H
- ⁽⁶⁾ Controlling dimension: inch

Document Number: 95014 Revision: 31-Mar-09

For technical questions within your region, please contact one of the following: <u>DiodesAmericas@vishay.com</u>, <u>DiodesAsia@vishay.com</u>, <u>DiodesEurope@vishay.com</u>

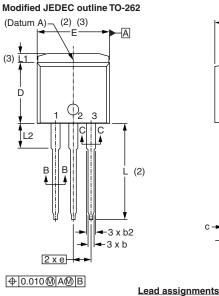
Outline Dimensions

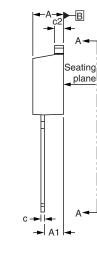
Vishay Semiconductors

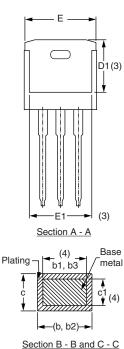
D²PAK, TO-262



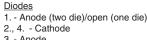
DIMENSIONS - TO-262 in millimeters and inches

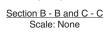






Lead tip





SYMBOL	MILLIN	METERS	INCI	NOTES	
	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.06	4.83	0.160	0.190	
A1	2.03	3.02	0.080	0.119	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
L	13.46	14.10	0.530	0.555	
L1	-	1.65	-	0.065	3
L2	3.56	3.71	0.140	0.146	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Controlling dimension: inches

www.vishay.com 2

For technical questions within your region, please contact one of the following:

DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com

actual package outline

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the

3. - Anode



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.